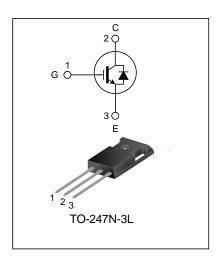
40A, 600V FIELD STOP IGBT

DESCRIPTION

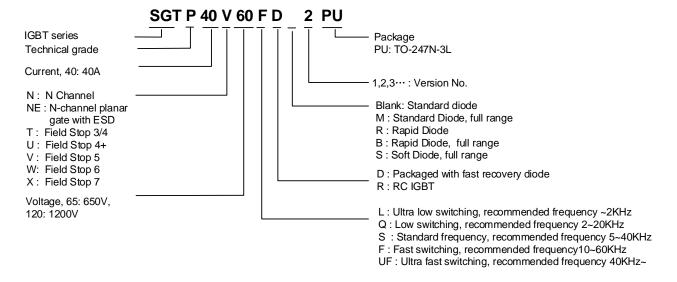
The SGTP40V60FD2PU field stop IGBT adopts Silan Field Stop V technology, features low conduction loss and switching loss. This device is applicable to photovoltaic, UPS, SMPS, and PFC fields.

FEATURES

- ◆ 40A, 600V, V_{CE(sat)(typ.)}=1.55V@I_C=40A
- Low conduction loss
- Ultra-fast switching
- High input impedance



NOMENCLATURE



ORDERING INFORMATION

Part No.	Package	Marking Hazardous Substance Control		Packing Type	
SGTP40V60FD2PU	TO-247N-3L	P40V60FD2	Halogen free	Tube	

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ABSOLUTE MAXIMUM RATINGS (UNLESS OTHERWISE NOTED, Tc=25°C)

Cha	aracteristics	Symbol	Ratings	Unit
Collector to Emitter	Voltage	V _{CE}	600	V
Gate to Emitter Volt	age	V_{GE}	±20	V
Transient Gate to E (t _p ≤10µs, D<0.010)	mitter Voltage	V _{GE}	±30	V
Callactor Current	T _C =25°C	lc -	80	А
Collector Current	Tc=100°C		40	
Pulsed Collector Cu	ırrent	Ісм	120	Α
Diode Current	T _C =25°C	- I _F	10	۸
Diode Current	T _C =100°C		5	A
Diode Pulsed Curre	ent	I _{FM}	15	Α
Power Dissipation (T _C =25°C)		PD	250	W
Operating Junction Temperature		TJ	-40∼+175	°C
Storage Temperatur	re Range	T _{stg}	-55∼+150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case (IGBT)	$R_{ heta JC}$				0.6	°C/W
Thermal Resistance, Junction to Case (FRD)	Rejc				3.5	°C/W
Thermal Resistance, Junction to Ambient (IGBT)	$R_{\theta JA}$				40	°C/W
Soldering Temperature (in line)	T _{sold}	15 ⁺² ₋₀ sec, 1time			260	°C

ELECTRICAL CHARACTERISTICS OF IGBT (UNLESS OTHERWISE NOTED, T_C=25°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Collector to Emitter	BVce	\\a=-0\\ la=2 5 0\\A	600			V
Breakdown Voltage	DACE	V _{GE} =0V, I _C =250μA	600			V
C-E Leakage Current	Ices	Vce=600V, Vge=0V			40	μΑ
G-E Leakage Current	IGES	V _{GE} =20V, V _{CE} =0V			±100	nA
G-E Threshold Voltage	V _{GE(th)}	Ic=250μA, Vc==Vge	3.2	4.5	5.8	V
Collector to Emitter	\/ ·	Ic=40A, Vge=15V, Tc=25°C		1.55	2.1	V
Saturation Voltage	V _{CE(sat)}	Ic=40A, Vge=15V, Tc=175°C		1.85		V
Input Capacitance	C _{ies}	Vce=30V		2909		
Output Capacitance	Coes	V _{GE} =0V		55		pF
Reverse Transfer Capacitance	Cres	f=1MHz		11		
Turn-On Delay Time	T _{d(on)}	V _{CE} =400V		47		
Rise Time	Tr	Ic=40A		24		
Turn-Off Delay Time	$T_{d(off)}$	R _g =10Ω		72		ns
Fall Time	T _f	V _{GE} =15V		25		

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Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Turn-On Switching Loss	Eon	inductive load		0.19		
Turn-Off Switching Loss	E _{off}	T _C =25°C		0.90		mJ
Total Switching Loss	Est			0.99		
Turn-On Delay Time	T _{d(on)}	1001/		50		
Rise Time	Tr	V _{CE} =400V		17		
Turn-Off Delay Time	T _{d(off)}	Ic=20A		77		ns
Fall Time	Tf	$R_{g}=10\Omega$		25		
Turn-On Switching Loss	Eon	V _{GE} =15V inductive load		0.04		
Turn-Off Switching Loss	E _{off}	Tc=25°C		0.40		mJ
Total Switching Loss	Est	10=25°C		0.44		
Total Gate Charge	Qg			110		
Gate to Emitter Charge	Q _{ge}	V _{CE} =480V, I _C =40A, V _{GE} =15V		23		nC
Gate to Collector Charge	Q_{gc}			29		

ELECTRICAL CHARACTERISTICS OF FRD (UNLESS OTHERWISE NOTED, Tc=25°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Diode Forward Voltage	\/	I _F =5A, T _C =25°C		1.4	2.0	V
	V _{FM}	I _F =5A, T _C =175°C		1.2		
Diode Reverse Recovery Time	Trr	L FA dl/dt 1000/up		39		ns
Diode Reverse Recovery Charge	Qrr	les=5A, dles/dt=100A/μs,		50		μC
Diode Reverse Recovery Current	Irm	V _R =50V, T _C =25°C		2.4		Α

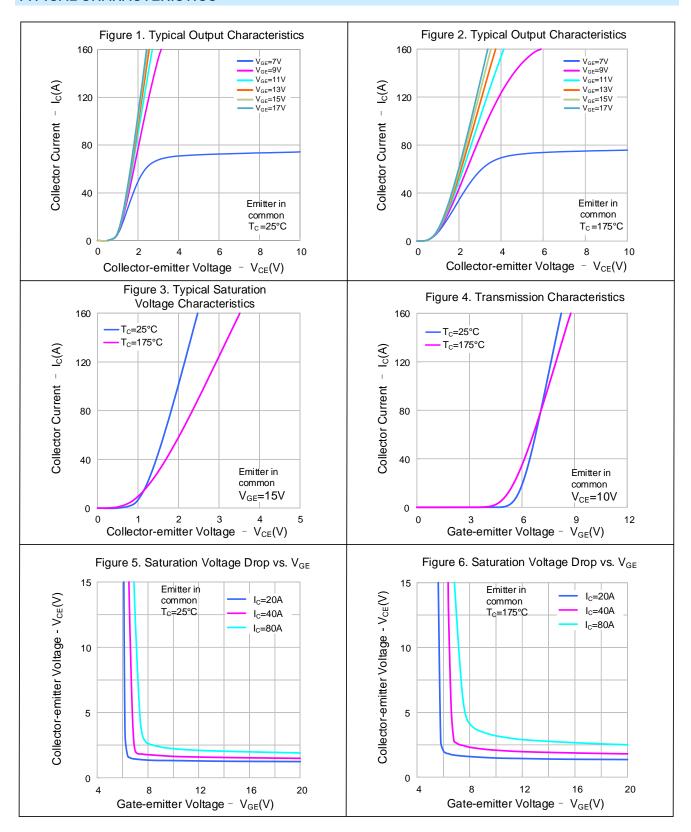
ELECTRICAL CHARACTERISTICS OF IGBT (UNLESS OTHERWISE NOTED, T_C=175°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Turn-On Delay Time	T _{d(on)}	1/ 4001/	-	45	-	
Rise Time	Tr	V _{CE} =400V		23		20
Turn-Off Delay Time	$T_{d(off)}$	Ic=40A		116		ns
Fall Time	T _f	$R_g=10\Omega$ $V_{GE}=15V$		28		
Turn-On Switching Loss	Eon	inductive load		0.23		
Turn-Off Switching Loss	E _{off}	T _C =175°C		1.15		mJ
Total Switching Loss	E _{st}	10-173 0		1.38		
Turn-On Delay Time	T _{d(on)}			49		
Rise Time	Tr	V _{CE} =400V		16		20
Turn-Off Delay Time	T _{d(off)}	Ic=20A		124		ns
Fall Time	Tf	$R_g=10\Omega$		32		
Turn-On Switching Loss	Eon	V _{GE} =15V inductive load		0.07		
Turn-Off Switching Loss	E _{off}	Tc=175°C		0.52		mJ
Total Switching Loss	E _{st}	10-173 0		0.59		

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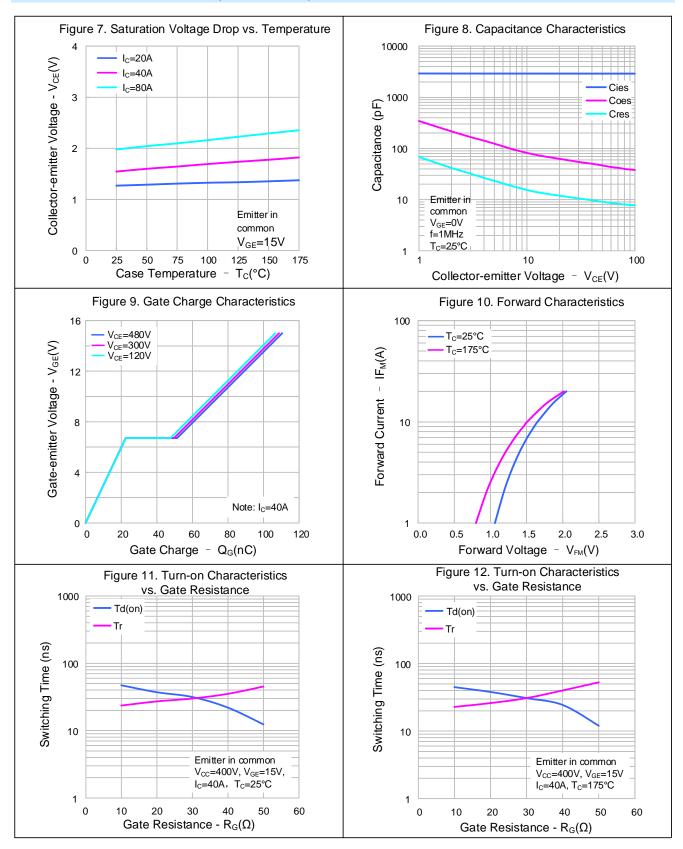
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS (CONTINUED)

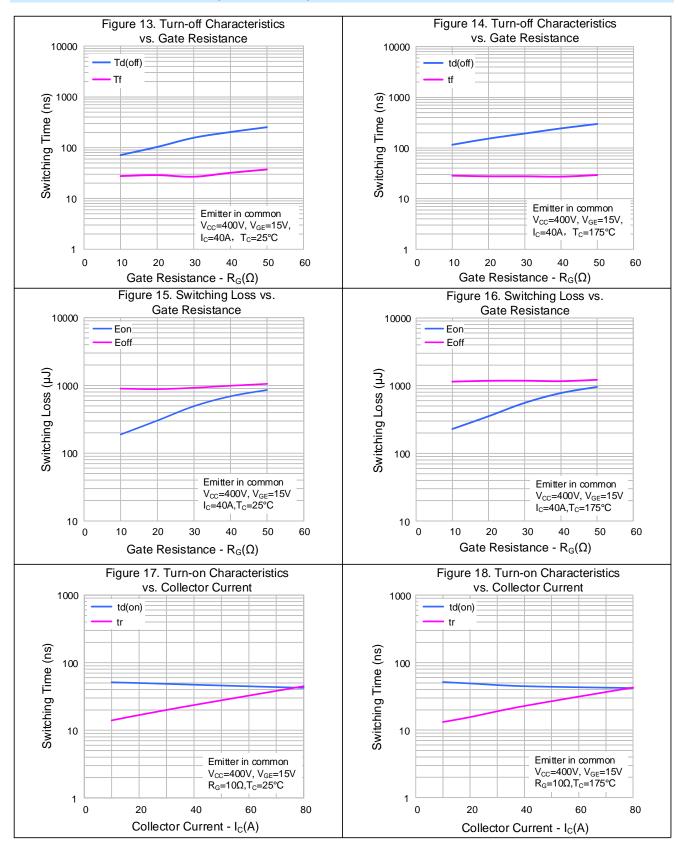


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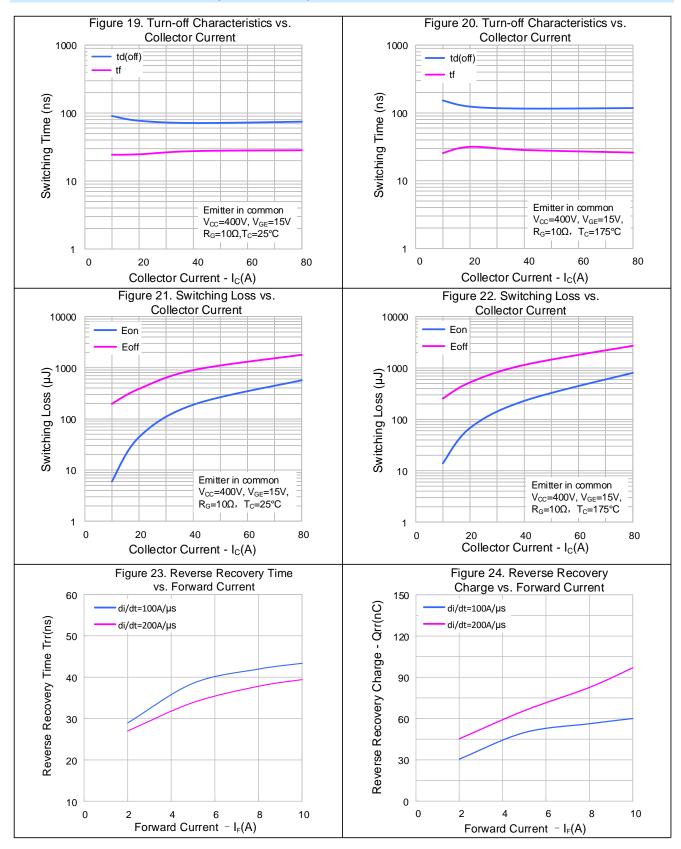
TYPICAL CHARACTERISTICS (CONTINUED)



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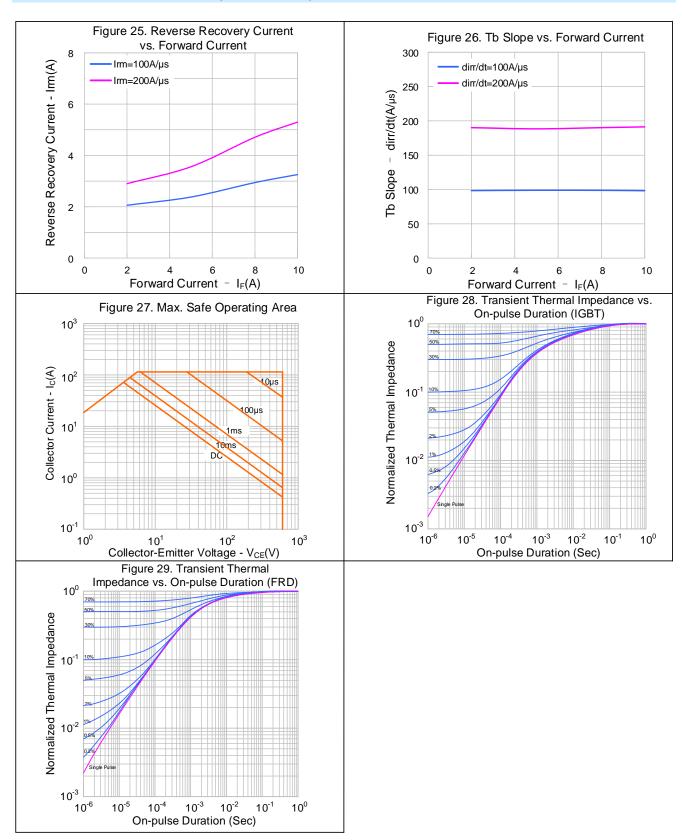
TYPICAL CHARACTERISTICS (CONTINUED)



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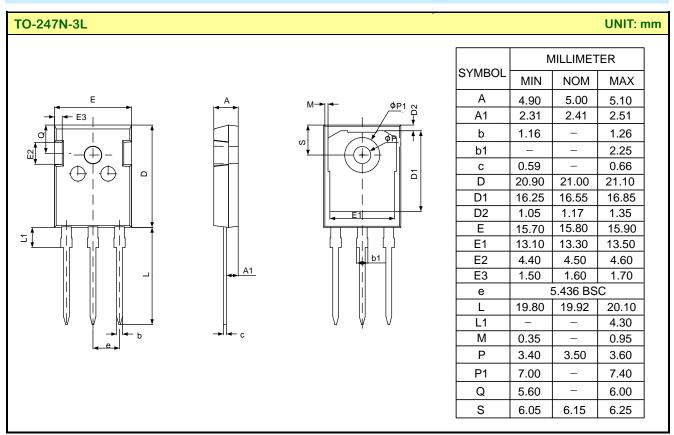
TYPICAL CHARACTERISTICS (CONTINUED)



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PACKAGE OUTLINE





MOS DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

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First release

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